

UNISONIC TECHNOLOGIES CO., LTD

UT134F/G **TRIAC**

TRIAC

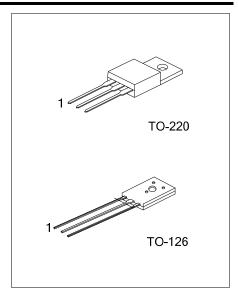
DESCRIPTION

The UTC UT134F/G is a triacs, it uses UTC's advanced technology to provide customers with high bidirectional transient and high thermal cycling performance.

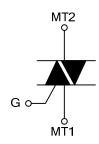
The UTC UT134F/G is suitable for motor control, heating and static switching, etc.

FEATURES

- * High bidirectional transient
- * High thermal cycling performance
- * Blocking voltage capability



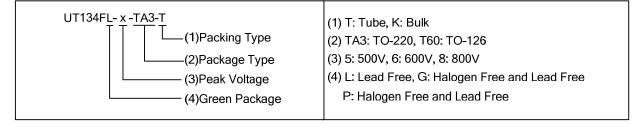
SYMBOL



ORDERING INFORMATION

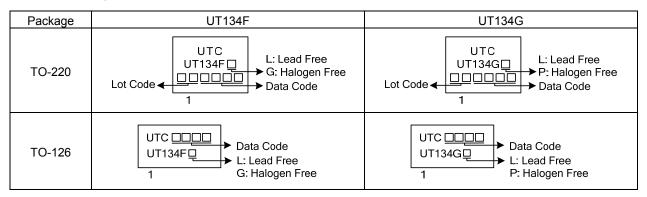
Order Number		Dookogo	Pin	Assignn	Dooking		
Normal	Lead Free Plating	Package	1	2	3	Packing	
UT134FL-x-TA3-T	UT134FG-x-TA3-T	TO-220	MT1	MT2	G	Tube	
UT134FL-x-T60-K	UT134FG-x-T60-K	TO-126	MT1	MT2	G	Bulk	
UT134GL-x-TA3-T	UT134GP-x-TA3-T	TO-220	MT1	MT2	G	Tube	
UT134GL-x-T60-K	-x-T60-K UT134GP-x-T60-K		MT1	MT2	G	Bulk	

Note: Pin Assignment: G: Gate



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■ MARKING



■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT	
	UT134F/G-5		500	V
Repetitive peak off-state voltages	UT134F/G-6	V_{DRM}	600 (Note 2)	V
	UT134F/G-8		800	V
RMS on-state current full sine wave; Tmb	≤107°C	I _{T(RMS)}	4	Α
Non-repetitive peak on-state current t = 20ms			25	Α
(Full sine wave; T _J = 25°C prior to surge)	t = 16.7 ms	I _{TSM}	27	А
I ² t for fusing	t = 10 ms	l ² t	3.1	A^2s
	T2+ G+		50	A/µs
Repetitive rate of rise of on-state current after triggering	T2+ G-	dl _⊤ /dt	50	A/µs
	T2- G-		50	A/µs
I_{TM} =20A; I_{G} =0.2A; d_{IG} /dt=0.2A/ μ s	T2- G+		10	A/µs
Peak gate voltage	V_{GM}	5	V	
Peak gate current	I_{GM}	2	Α	
Peak gate power	P_GM	5	W	
Average gate power (over any 20 ms period	$P_{G(AV)}$	0.5	W	
Junction Temperature		T_J	+125	°C
Storage Temperature		T_{STG}	-40 ~ +150	°C

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL RESISTANCES

PARAMETER		SYMBOL	MIN	TYP	MAX	UNIT	
Junction to Ambient	In Free Air	TO-220	θ_{JA}		60		°C/W
		TO-126			100		°C/W
Junction to mounting base	Full cycle	TO-220	θ _{JC}			2.0	°C/W
		TO-126				3.0	°C/W
	Half cycle	TO-220				2.4	°C/W
		TO-126				3.7	°C/W

■ STATIC CHARACTERISTICS (T_J =25°C, unless otherwise specified)

DADAMETED	SYMBOL	TEST CONDITIONS MIN		MINI	TYP	MAX		UNIT
PARAMETER	STIVIBUL			ITP	UT134F	UT134G	UNIT	
	I _{GT}	V _D =12V, I _T =0.1A	T2+G+		5	25	50	mA
Cata Trigger Current			T2+G-		8	25	50	
Gate Trigger Current			T2-G-		11	25	50	
			T2-G+		30	70	100	
	IL	V _D =12V, I _{GT} =0.1A	T2+G+		7	20	30	mA
Latching Current			T2+G-		16	30	45	
			T2-G-		5	20	30	
			T2-G+		7	30	45	
Holding Current	I _H	V _D =12V, I _{GT} =0.1A			5	15	30	mA
On-State Voltage	V_{T}	I _T =5A			1.4	1.7		V
Gate Trigger Voltage	V_{GT}	V _D =12V, I _T =0.1A			0.7	1.5		V
		V _D =400V, I _T =0.1A, T _J =125°C		0.25	0.4			V
Off-State Leakage Current	I_{D}	V _D =V _{DRM(max)} , T _J =125°C			0.1	0.5		mA

^{2.} Although not recommended, off-state voltages up to 800V may be applied without damage, but the traic may switch to the on-state. The rate of rise of current should not exceed 3A/µs.

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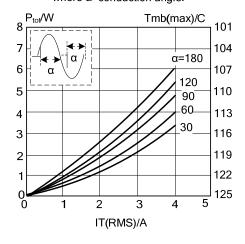
■ **DYNAMIC CHARACTERISTICS** (T_J =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN		TYP	MAY	UNIT
TANAMETER	STWIDOL	TEST CONDITIONS	UT134F	UT134G	1 11	IVIAX	CIVII
Critical Rate Of Rise Of		V _{DM} =67% V _{DRM(max)} , T _J =125°C,	50	200	250		V/µs
Off-State Voltage	u v _D /ut	Exponential waveform, gate open circuit	50	200	250		ν/μ5
Critical Rate Of Change		V -400V T -05°C L -4A					
Of Commutating	dV _{com} /dt	V _{DM} =400V, T _J =95°C, I _{T(RMS)} =4A, dI _{com} /dt=1.8A/ms, gate open circuit		10	20		V/µs
Voltage		di _{com} /di=1.6A/ms, gate open dicuit					
Gate Controlled	4	I_{TM} =26A, V_D = $V_{DRM(max)}$, I_G =0.1A,			2		
Turn-On Time	t _{gt}	dI _G /dt=5A/µs					μs

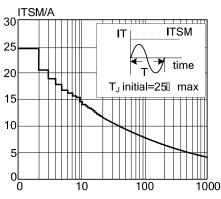
UT134F/G TRIAC

■ TYPICAL CHARACTERISTICS

Maximum On-State Dissipation, P_{tot} Versus Rms On-state Current, $I_{T(RMS)}$ where α =conduction angle.

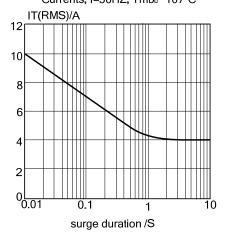


Maximum Permissible Non-repetitive Peak On-state Current, I_{TSM}, Versus Number Of Cycles, For Sinusoidal Currents, f=50HZ.

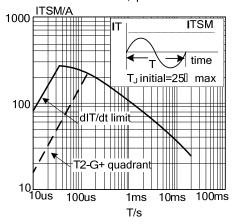


Number of cycles at 50Hz

Maximum Permissible Repetitive Rms On-State Current , I_{T(RMS)} ,Versus Surge Duration, For Sinusoidal Currents, f=50HZ, Tmbl 107°C



Maximum Permissible Non-repetitive Peak On-state Current, ITSM, Versus Pulse Width tp For Sinusoidal Currents, tpl 20ms



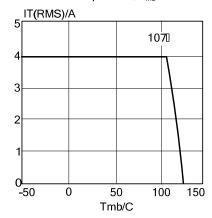
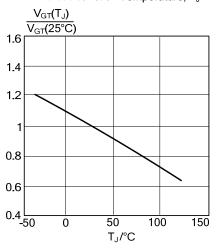
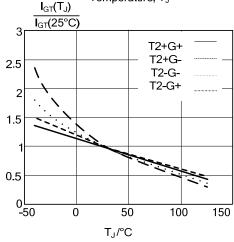


Fig 6. Normalised Gate Trigger Voltage, V_{GT}(T_J)/V_{GT}(25°C), Versus Junction Temperature, T_J

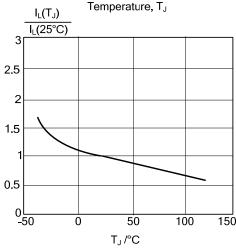


TYPICAL CHARACTERISTICS

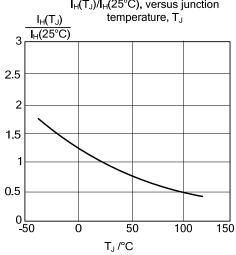
Normalised Gate Trigger Current, I_{GT}(T_J)/I_GT(25°C), VersusJunction Temperature, T_J



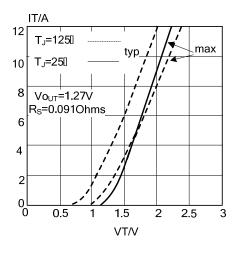
Normalised Latching Current, I_L(T_J)/I_L(25°C) Versus Junction



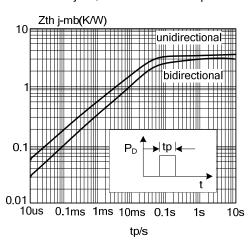
Normalised Holding Current, I_H(T_J)/I_H(25°C), versus junction



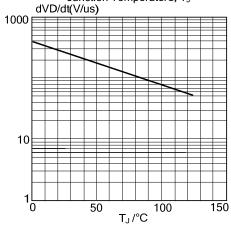
Typical And Maximum On-state Characteristic



Transient Thermal Impedance Zthj-mb, Versus Pulse Width tp



Typical Critical Rate Of Rise Of Offsatate Voltage, DVD/dt Versus Junction Temperature, T_J



UT134F/G

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